

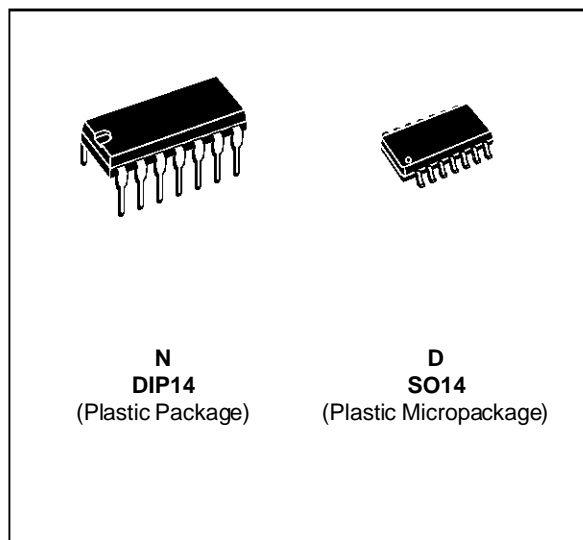
LOW POWER QUAD OPERATIONAL AMPLIFIERS

- WIDE GAIN BANDWIDTH / 1.3MHz
- LARGE VOLTAGE GAIN : 100dB
- VERY LOW SUPPLY CURRENT/AMPLI : 375µA
- LOW INPUT BIAS CURRENT : 20nA
- LOW INPUT OFFSET VOLTAGE : 3mV max.
- LOW INPUT OFFSET CURRENT : 2nA
- WIDE POWER SUPPLY RANGE :
SINGLE SUPPLY : +3V TO +30V
DUAL SUPPLIES : ±1.5V TO ±15V
- INPUT COMMON-MODE VOLTAGE RANGE INCLUDES GROUND
- ESD INTERNAL PROTECTION : 2kV

DESCRIPTION

These circuits consist of four independent, high gain, internally frequency compensated operational amplifiers. They operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage.

All the pins are protected against electrostatic discharges up to 2000V (as a consequence, the input voltages must not exceed the magnitude of V_{CC}^+ or V_{CC}^- .)

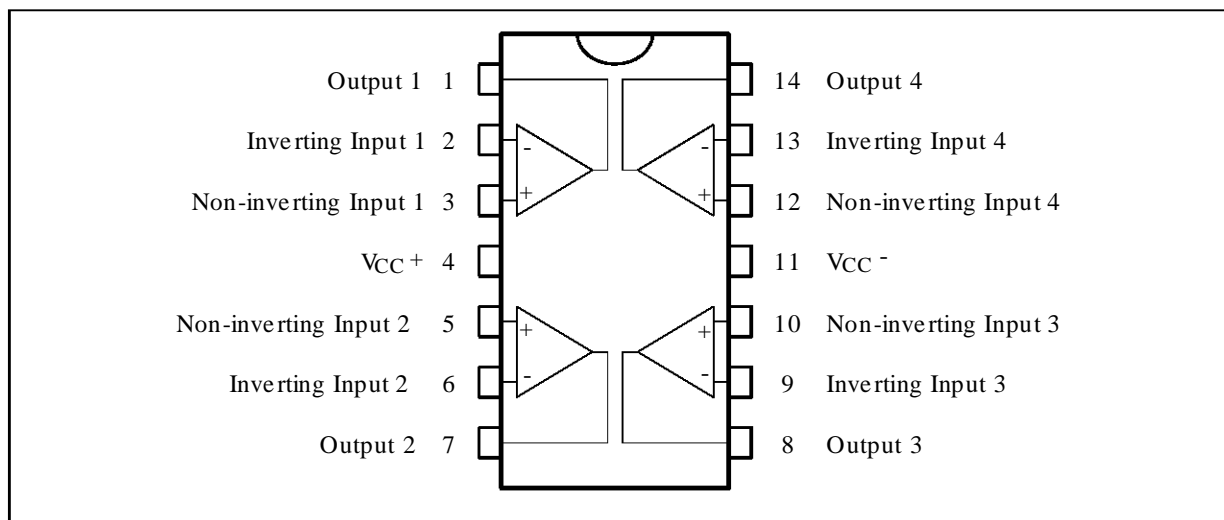


ORDER CODES

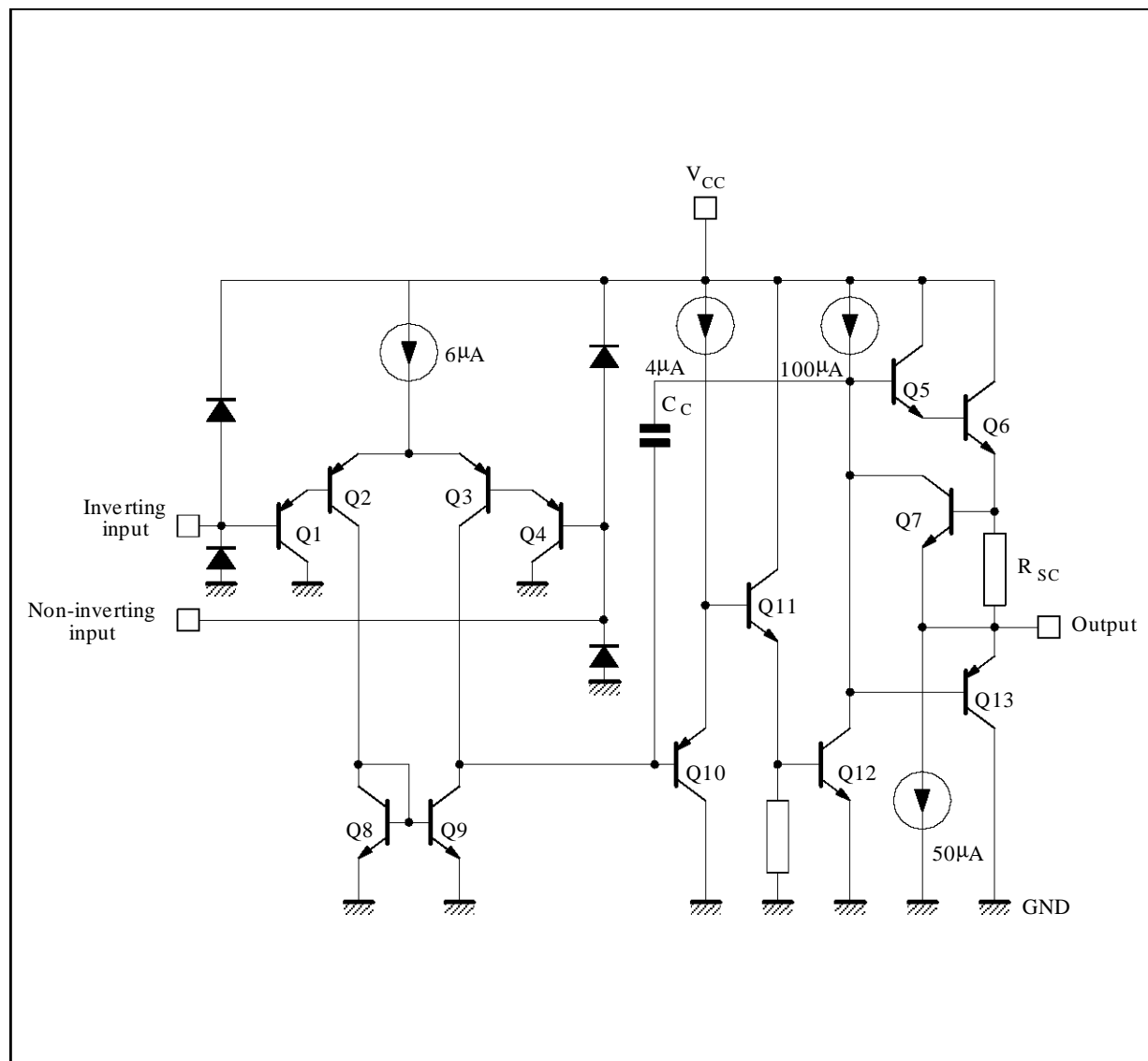
Part Number	Temperature Range	Package	
		N	D
LM124A	-55°C, +125°C	•	•
LM224A	-40°C, +105°C	•	•
LM324A	0°C, +70°C	•	•

Example : LM224AN

PIN CONNECTIONS (top view)



SCHEMATIC DIAGRAM (1/4 LM124A)



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	LM124A	LM224A	LM324A	Unit
V_{cc}	Supply Voltage	± 16 or 32			V
V_i	Input Voltage	-0.3 to +32			V
V_{id}	Differential Input Voltage - (*)	+32	+32	+32	V
P_{tot}	Power Dissipation N Suffix D Suffix	500 -	500 400	500 400	mW mW
-	Output Short-circuit Duration - (note 1)	Infinite			
I_{in}	Input Current - (note 6)	50	50	50	mA
T_{oper}	Operating Free Air Temperature Range	-55 to +125	-40 to +105	0 to +70	°C
T_{stg}	Storage Temperature Range	-65 to +150	-65 to +150	-65 to +150	°C

(*) - Either or both input voltages must not exceed the magnitude of V_{cc}^+ or V_{cc}^- .

ELECTRICAL CHARACTERISTICS

$V_{CC}^+ = +5V$, $V_{CC}^- = \text{Ground}$, $V_O = 1.4V$, $T_{amb} = +25^\circ C$ (unless otherwise specified)

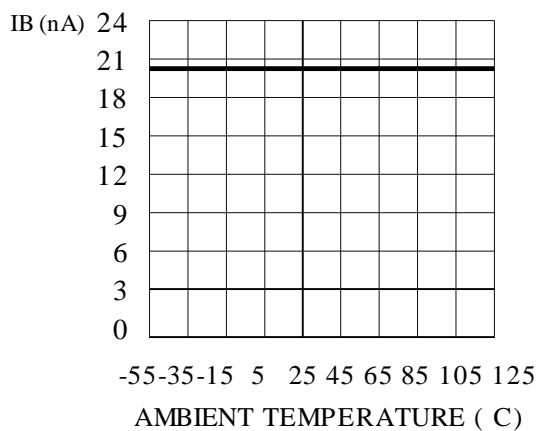
Symbol	Parameter	LM124A - LM224A - LM324A			Unit
		Min.	Typ.	Max.	
V_{io}	Input Offset Voltage (note 3) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		2	3 5	mV
I_{io}	Input Offset Current $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		2	20 40	nA
I_{ib}	Input Bias Current (note 2) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		20	100 200	nA
A_{vd}	Large Signal Voltage Gain ($V_{CC}^+ = +15V$, $R_L = 2k\Omega$, $V_O = 1.4V$ to $11.4V$) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	50 25	100		V/mV
SVR	Supply Voltage Rejection Ratio ($R_S \leq 10k\Omega$) ($V_{CC}^+ = 5V$ to $30V$) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	65 65	110		dB
I_{CC}	Supply Current, all Amp, no load $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$ $V_{CC} = +5V$ $V_{CC} = +30V$ $V_{CC} = +5V$ $V_{CC} = +30V$		0.7 1.5 0.8 1.5	1.2 3 1.2 3	mA
V_{icm}	Input Common Mode Voltage Range ($V_{CC} = +30V$) - (note 4) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	0 0		$V_{CC} - 1.5$ $V_{CC} - 2$	V
CMR	Common-mode Rejection Ratio ($R_S \leq 10k\Omega$) $T_{amb} = +25^\circ C$ $T_{min.} \leq T_{amb} \leq T_{max.}$	70 60	80		dB
I_{source}	Output Current Source ($V_{id} = +1V$) $V_{CC} = +15V$, $V_O = +2V$	20	40	70	mA
I_{sink}	Output Sink Current ($V_{id} = -1V$) $V_{CC} = +15V$, $V_O = +2V$ $V_{CC} = +15V$, $V_O = +0.2V$	10 12	20 50		mA μA

ELECTRICAL CHARACTERISTICS (continued)

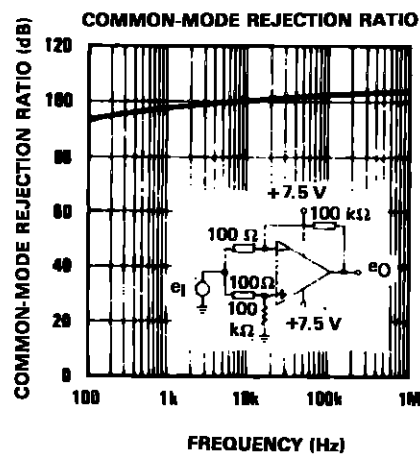
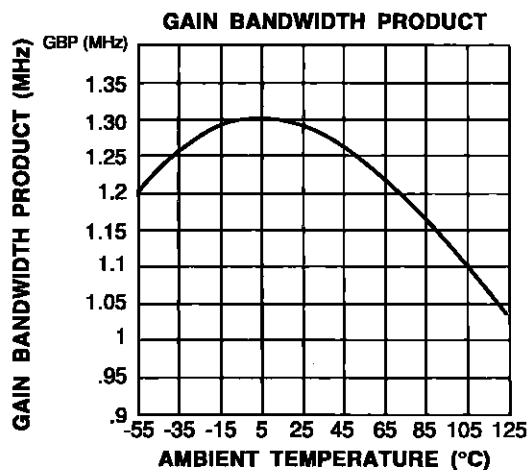
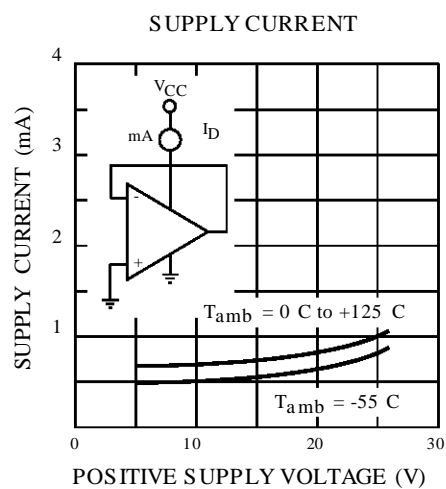
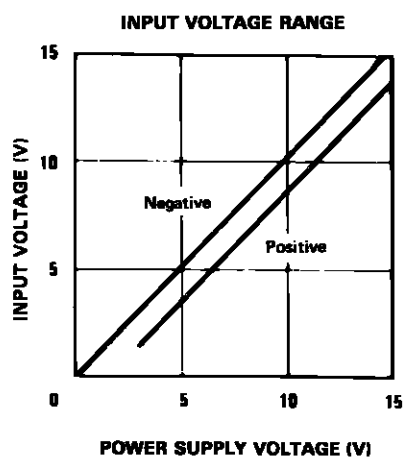
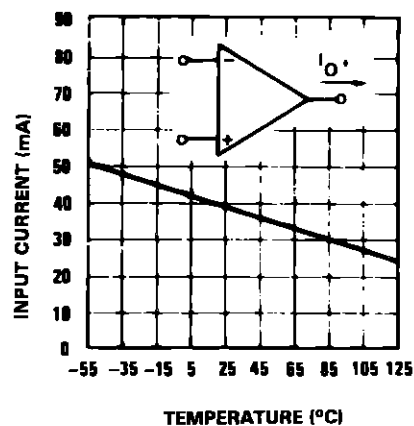
Symbol	Parameter	LM124A - LM224A - LM324A			Unit
		Min.	Typ.	Max.	
V_{OH}	High Level Output Voltage ($V_{CC} = +30V$) $T_{amb} = +25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$ $T_{amb} = +25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$ ($V_{CC} = +5V, R_L = 2k\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$ $R_L = 10k\Omega$	26 26 27 27 3.5 3	27 28		V
V_{OL}	Low Level Output Voltage ($R_L = 10k\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min.} \leq T_{amb} \leq T_{max.}$		5	20 20	mV
SR	Slew Rate ($V_{CC} = 15V, V_I = 0.5$ to $3V$, $R_L = 2k\Omega, C_L = 100pF$, unity gain)		0.4		V/ μs
GBP	Gain Bandwidth Product ($V_{CC} = 30V$ $f = 100kHz, V_{in} = 10mV$ $R_L = 2k\Omega, C_L = 100pF$)		1.3		MHz
THD	Total Harmonic Distortion ($f = 1kHz, A_V = 20dB, R_L = 2k\Omega, V_O = 2V_{pp}$ $C_L = 100pF, V_{CC} = 30V$)		0.015		%
e_n	Equivalent Input Noise Voltage ($f = 1kHz, R_s = 100\Omega, V_{CC} = 30V$)		40		$\frac{nV}{\sqrt{Hz}}$
DV_{IO}	Input Offset Voltage Drift		7	30	$\mu V/^{\circ}C$
DI_{IO}	Input Offset Current Drift		10	200	$pA/^{\circ}C$
V_{O1}/V_{O2}	Channel Separation (note 5) $1kHz \leq f \leq 20kHz$		120		dB

- Notes :**
1. Short-circuits from the output to V_{CC} can cause excessive heating if $V_{CC} > 15V$. The maximum output current is approximately 40mA independent of the magnitude of V_{CC} . Destructive dissipation can result from simultaneous short-circuit on all amplifiers.
 2. The direction of the input current is out of the IC. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.
 3. $V_O = 1.4V, R_s = 0\Omega, 5V < V_{CC} < 30V, 0 < V_{IC} < V_{CC} - 1.5V$
 4. The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is $V_{CC} - 1.5V$, but either or both inputs can go to +32V without damage.
 5. Due to the proximity of external components insure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.
 6. This input current only exists when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistor becoming forward biased and thereby acting as input diodes clamps. In addition to this diode action, there is also NPN parasitic action on the IC chip. this transistor action can cause the output voltages of the Op-amps to go to the V_{CC} voltage level (or to ground for a large overdrive) for the time duration than an input is driven negative.
This is not destructive and normal output will set up again for input voltage higher than -0.3V.

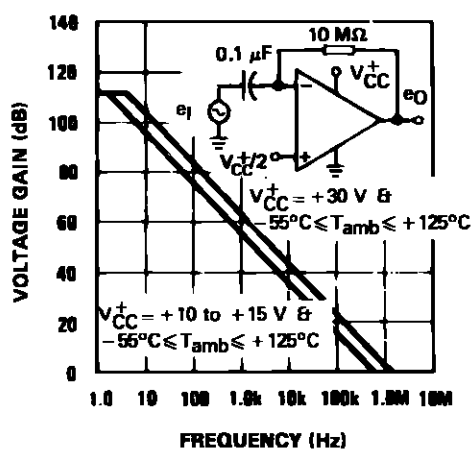
INPUT BIAS CURRENT
versus AMBIENT TEMPERATURE



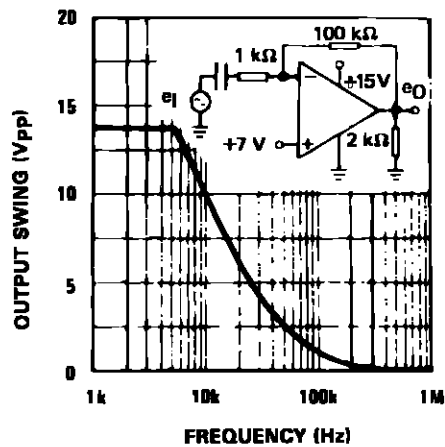
CURRENT LIMITING (Note 8)



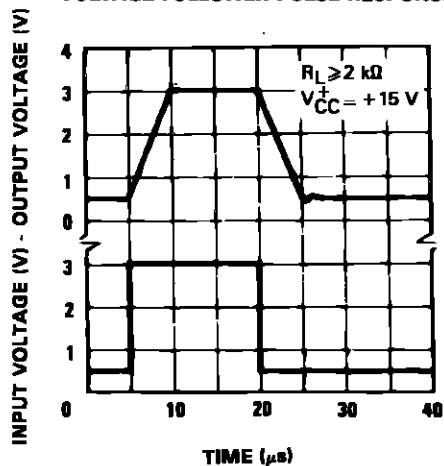
OPEN LOOP FREQUENCY RESPONSE



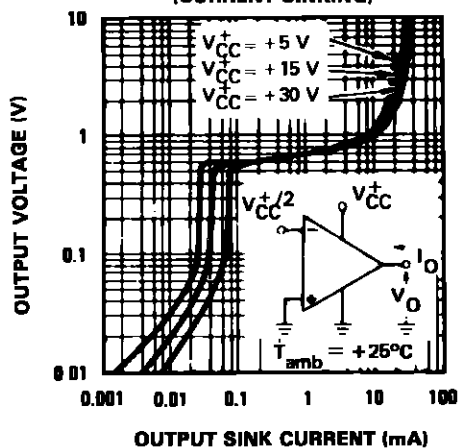
LARGE SIGNAL FREQUENCY RESPONSE



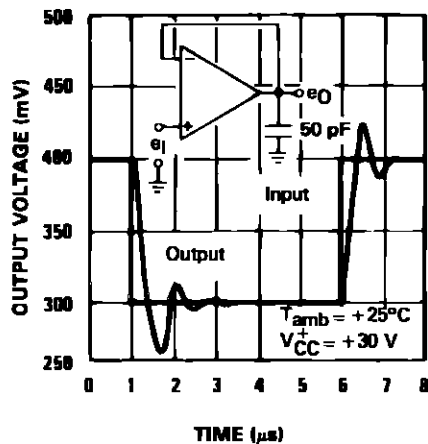
VOLTAGE FOLLOWER PULSE RESPONSE



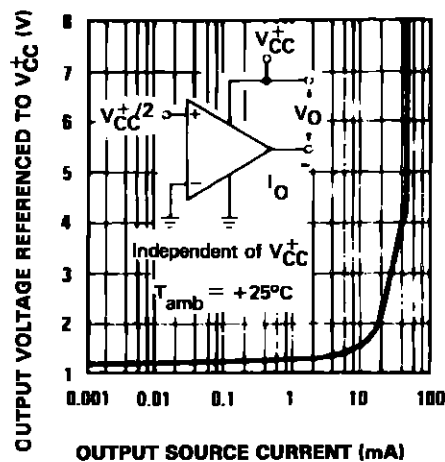
OUTPUT CHARACTERISTICS (CURRENT SINKING)

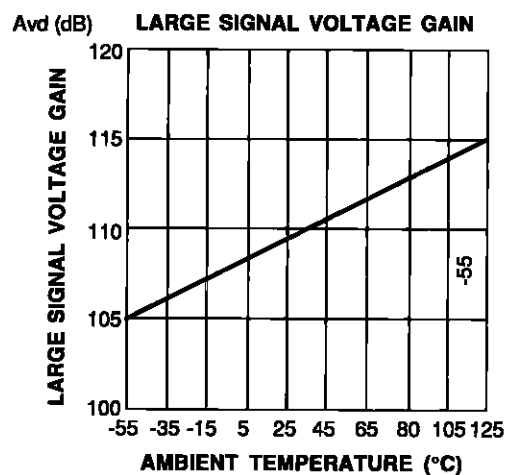
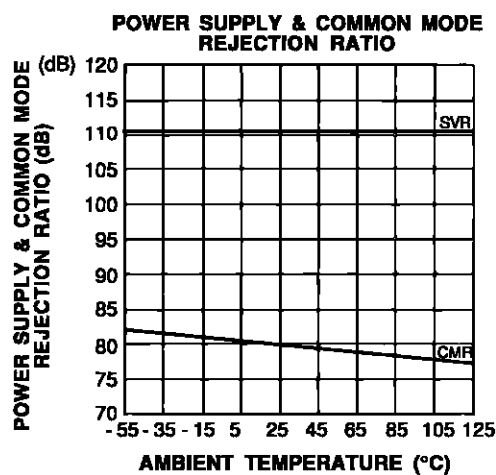
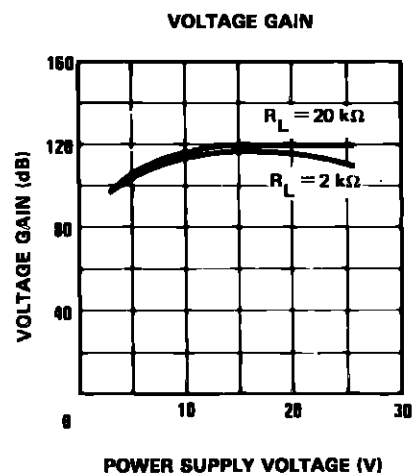
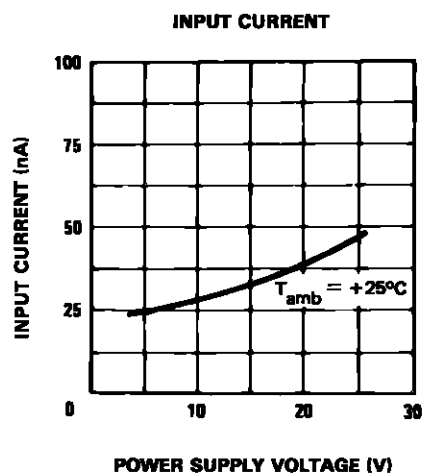


VOLTAGE FOLLOWER PULSE RESPONSE (SMALL SIGNAL)



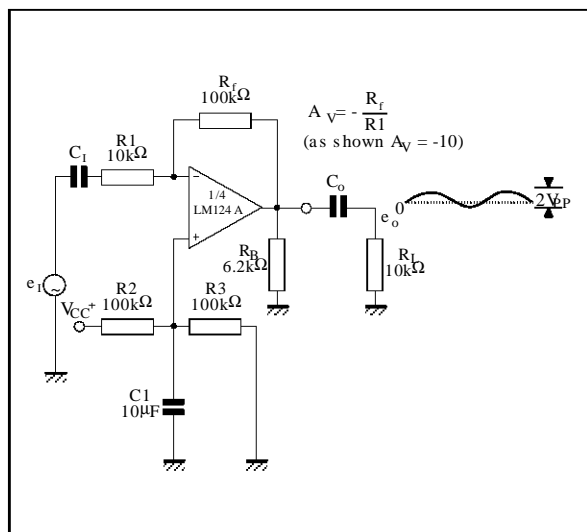
OUTPUT CHARACTERISTICS (CURRENT SOURCING)



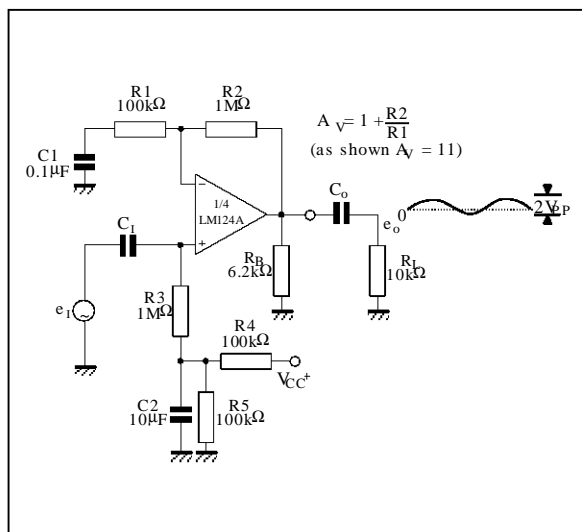


TYPICAL SINGLE - SUPPLY APPLICATIONS

AC COUPLED INVERTING AMPLIFIER

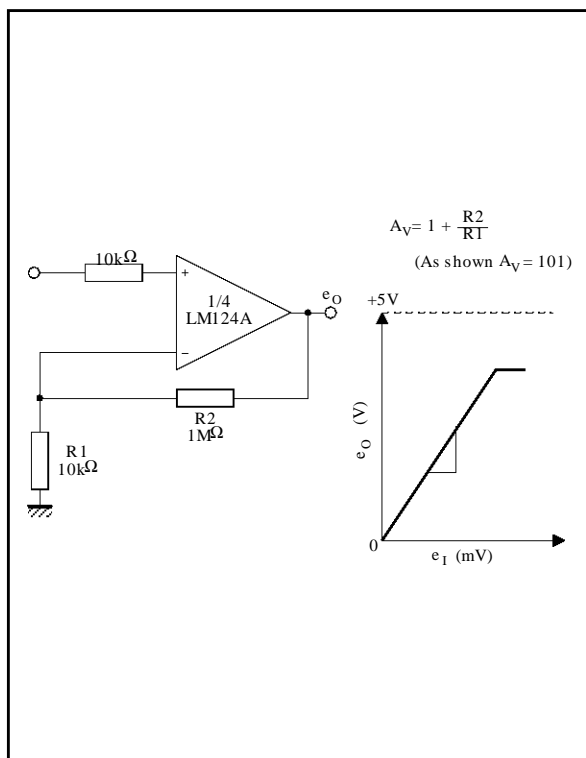


AC COUPLED NON-INVERTING AMPLIFIER

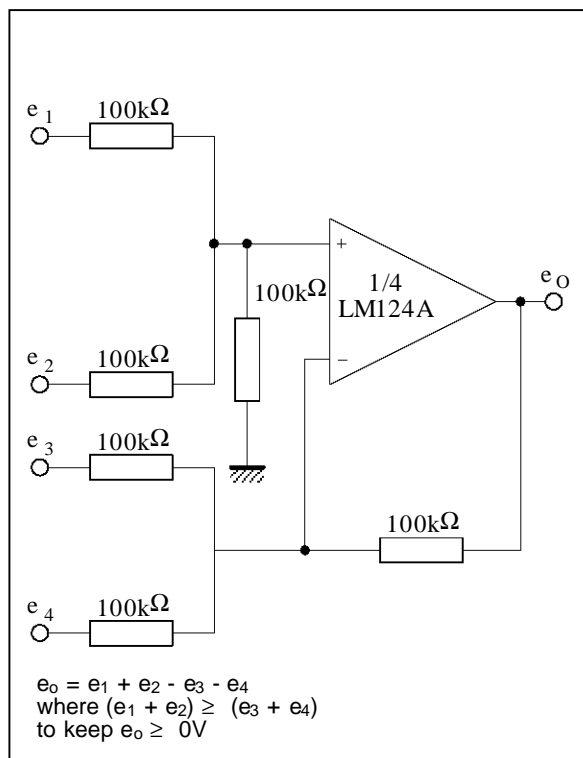


TYPICAL SINGLE - SUPPLY APPLICATIONS

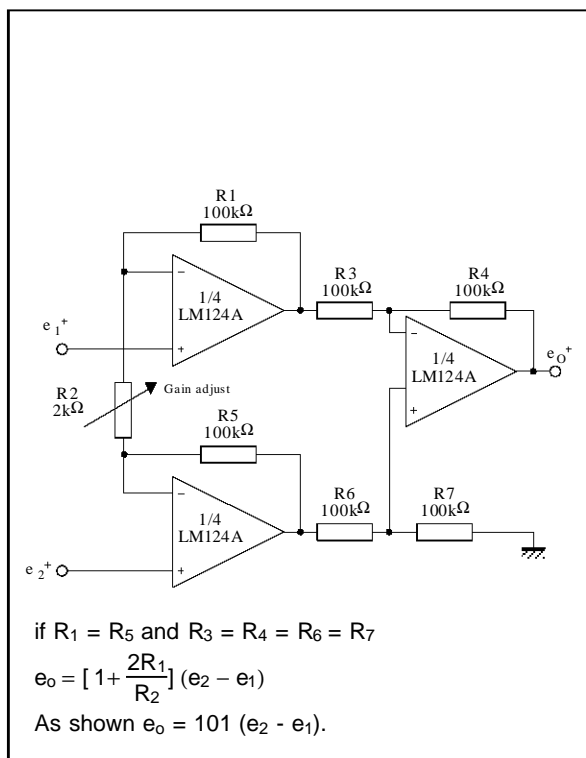
NON-INVERTING DC GAIN



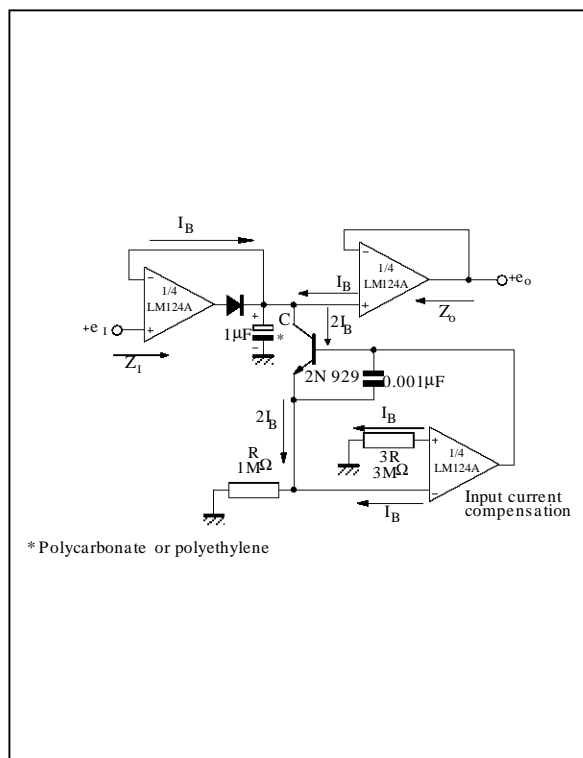
DC SUMMING AMPLIFIER



HIGH INPUT Z ADJUSTABLE GAIN DC INSTRUMENTATION AMPLIFIER

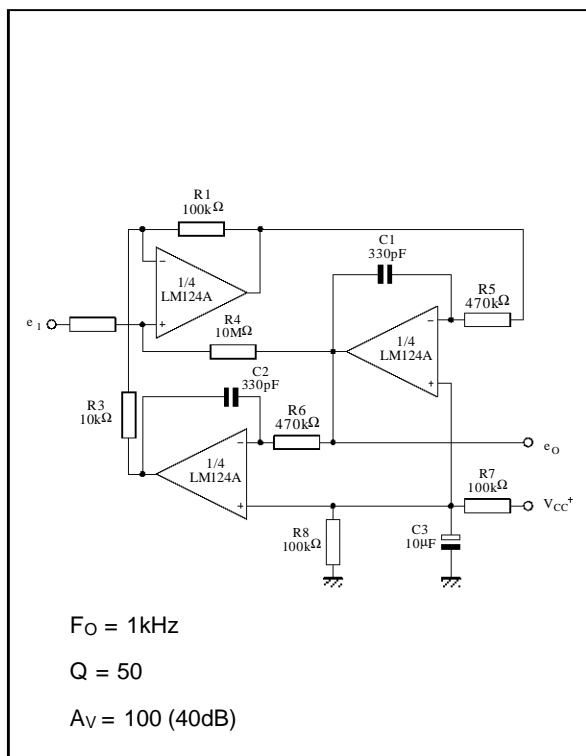


LOW DRIFT PEAK DETECTOR



TYPICAL SINGLE - SUPPLY APPLICATIONS

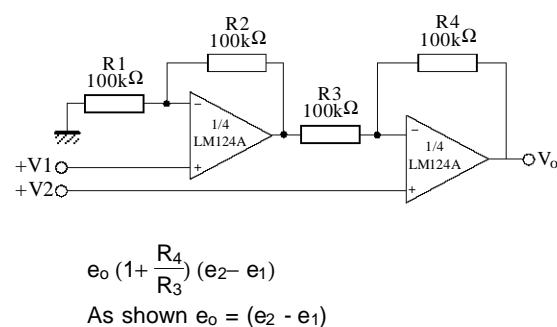
ACTIVER BANDPASS FILTER



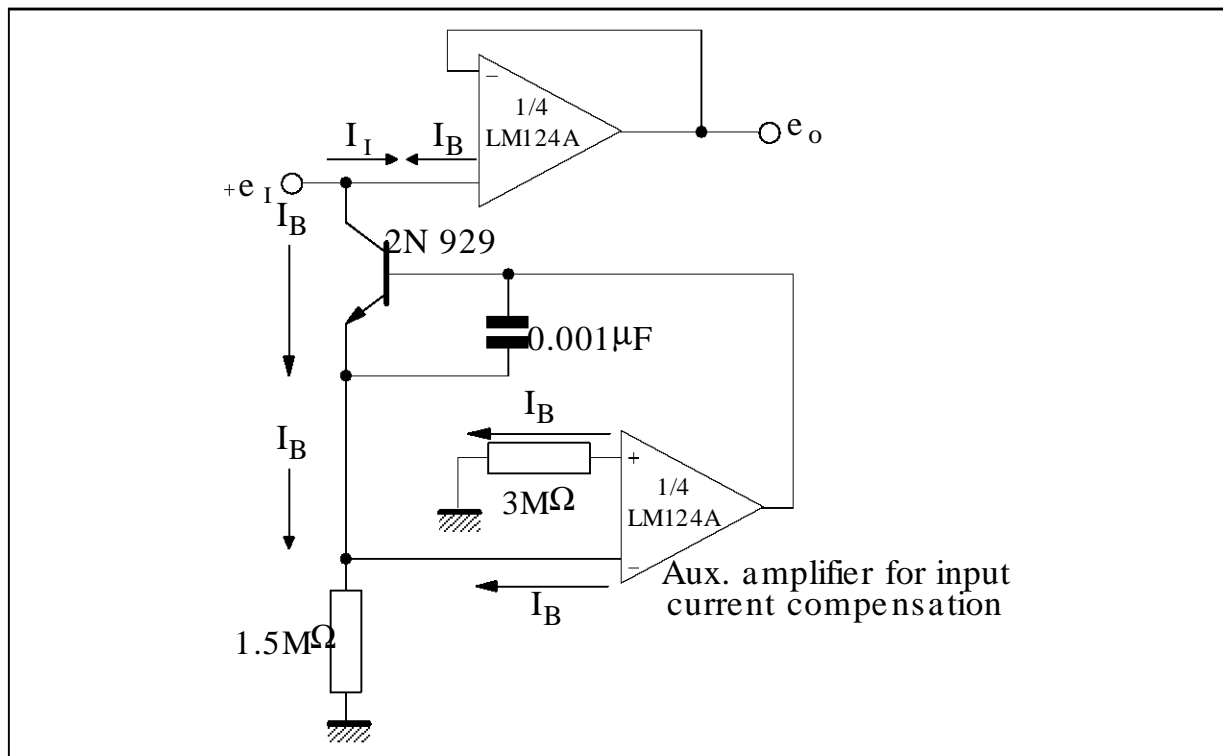
HIGH INPUT Z, DC DIFFERENTIAL AMPLIFIER

$$\text{For } \frac{R_1}{R_2} = \frac{R_4}{R_3}$$

(CMRR depends on this resistor ratio match)



USING SYMMETRICAL AMPLIFIERS TO REDUCE INPUT CURRENT (GENERAL CONCEPT)



LM124A - LM224A - LM324A

- LARGE VOLTAGE GAIN : 100dB
- VERY LOW SUPPLY CURRENT/AMPLI : 375 μ A
- LOW INPUT BIAS CURRENT : 20nA
- LOW INPUT OFFSET VOLTAGE : 2mV
- LOW INPUT OFFSET CURRENT : 2nA
- WIDE POWER SUPPLY RANGE :
SINGLE SUPPLY : +3V to +30V
DUAL SUPPLIES : ± 1.5 V to ± 15 V

Applies to : LM124A-LM224A-LM324A

** Standard Linear Ics Macromodels, 1993.

** CONNECTIONS :

* 1 INVERTING INPUT

* 2 NON-INVERTING INPUT

* 3 OUTPUT

* 4 POSITIVE POWER SUPPLY

* 5 NEGATIVE POWER SUPPLY

.SUBCKT LM124 1 3 2 4 5 (analog)

.MODEL MDTH D IS=1E-8 KF=3.104131E-15
CJO=10F

* INPUT STAGE

CIP 2 5 1.000000E-12

CIN 1 5 1.000000E-12

EIP 10 5 2 5 1

EIN 16 5 1 5 1

RIP 10 11 2.600000E+01

RIN 15 16 2.600000E+01

RIS 11 15 2.003862E+02

DIP 11 12 MDTH 400E-12

DIN 15 14 MDTH 400E-12

VOFP 12 13 DC 0

VOFN 13 14 DC 0

IPOL 13 5 1.000000E-05

CPS 11 15 3.783376E-09

DINN 17 13 MDTH 400E-12

VIN 17 5 0.000000E+00

DINR 15 18 MDTH 400E-12

VIP 4 18 2.000000E+00

FCP 4 5 VOFP 3.400000E+01

FCN 5 4 VOFN 3.400000E+01

FIBP 2 5 VOFN 2.000000E-03

FIBN 5 1 VOFP 2.000000E-03

* AMPLIFYING STAGE

FIP 5 19 VOFP 3.600000E+02

FIN 5 19 VOFN 3.600000E+02

RG1 19 5 3.652997E+06

RG2 19 4 3.652997E+06

CC 19 5 6.000000E-09

DOPM 19 22 MDTH 400E-12

DONM 21 19 MDTH 400E-12

HOPM 22 28 VOUT 7.500000E+03

VIPM 28 4 1.500000E+02

HONM 21 27 VOUT 7.500000E+03

VINM 5 27 1.500000E+02

EOUT 26 23 19 5 1

VOUT 23 5 0

ROUT 26 3 20

COU 3 5 1.000000E-12

DOP 19 25 MDTH 400E-12

VOP 4 25 2.242230E+00

DON 24 19 MDTH 400E-12

VON 24 5 7.922301E-01

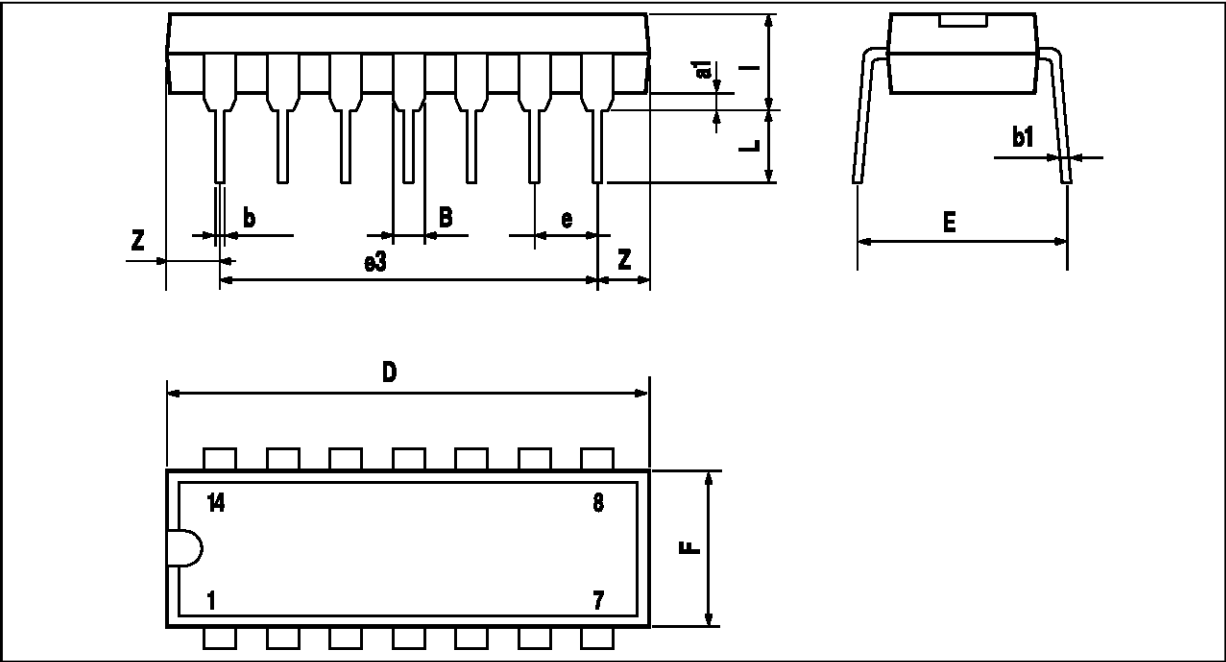
.ENDS

ELECTRICAL CHARACTERISTICS

$V_{CC}^{+} = +5V$, $V_{CC}^{-} = 0V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

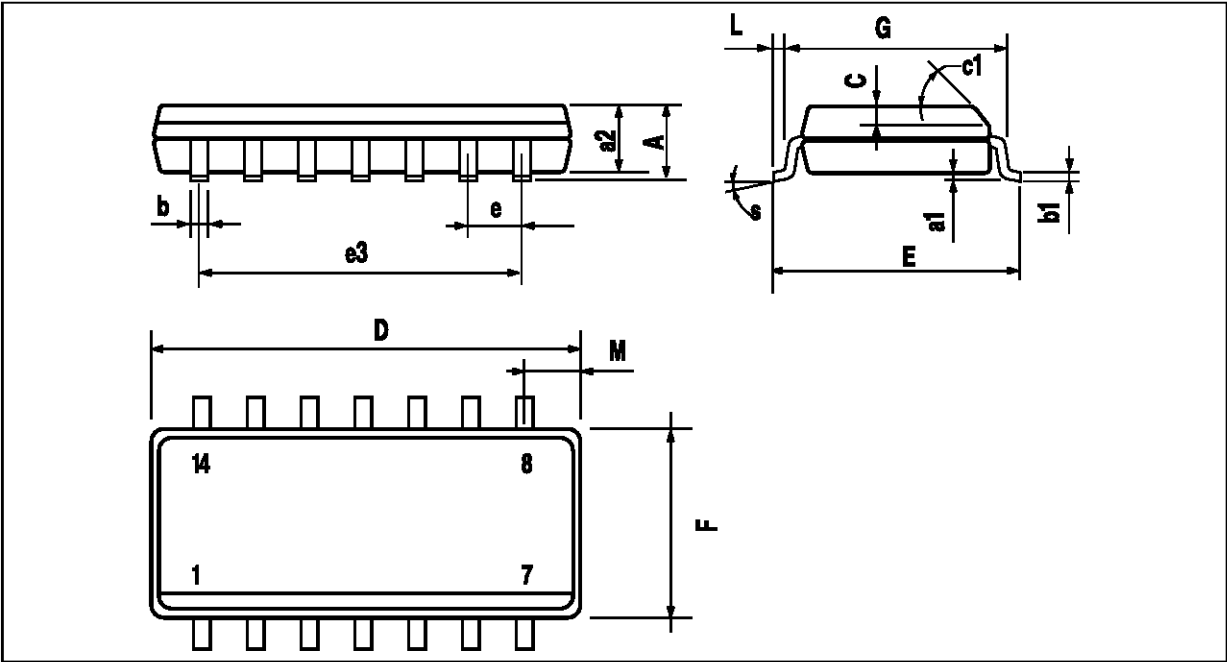
Symbol	Conditions	Value	Unit
V_{io}		0	mV
A_{vd}	$R_L = 2k\Omega$	100	V/mV
I_{CC}	No load, per operator	350	μA
V_{icm}		-15 to +13.5	V
V_{OH}	$R_L = 2k\Omega$ ($V_{CC}^{+} = 15V$)	+13.5	V
V_{OL}	$R_L = 10k\Omega$	5	mV
I_{OS}	$V_O = +2V$, $V_{CC} = +15V$	+40	mA
GBP	$R_L = 2k\Omega$, $C_L = 100pF$	1.3	MHz
SR	$R_L = 2k\Omega$, $C_L = 100pF$	0.4	V/ μs

PACKAGE MECHANICAL DATA
14 PINS - PLASTIC DIP



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

PACKAGE MECHANICAL DATA
14 PINS - PLASTIC MICROPACKAGE (SO)



Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.2	0.004		0.008
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.334
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.020		0.050
M			0.68			0.027
S	8° (max.)					

Vertical text on the right side of the table: SO14.TBL

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